

570548/60
0270 2. Pro

	Class	Subclass
ISSUE CLASSIFICATION		

PATENT NUMBER

U.S. UTILITY Patent Application

<p>MA O.I.P.E. SCANNED Q.A. <i>EW</i></p>	<p>PATENT DATE</p>
---	--------------------

APPLICATION NO. 09/845845	CONT/PRIOR	CLASS 313	SUBCLASS 311	ART UNIT 2879	EXAMINER PHINNEY
------------------------------	------------	--------------	-----------------	------------------	---------------------

SUBJECTS Xia Sheng
Nobuyoshi Kashiida
Huei-Pai Yoo

Silicon emitter with low porosity heavily doped contact layer

PTO-2040
12/89

ISSUING CLASSIFICATION

ORIGINAL		CROSS REFERENCE(S)			
	SUBCLASS	CLASS	SUBCLASS (ONE SUBCLASS)		
INTERNATIONAL CLASSIFICATION					
	1/312				
	19/27				

Continued on 1580 Slip in 1580 Slip Box

<input type="checkbox"/> TERMINAL DISCLAIMER	DRAWINGS Sheets Drwg. Figs. Drwg. Print Fig.		CLAIMS ALLOWED Total Claims Print Claim for O.G.	
<input type="checkbox"/> The term of this patent subsequent to _____ (date) has been disclaimed.	_____ (Assistant Examiner) (Date)		NOTICE OF ALLOWANCE MAILED	
<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S. Patent No. _____	_____ (Primary Examiner) (Date)		ISSUE FEE Amount Due Date Paid	
<input type="checkbox"/> The terminal _____ months of this patent have been disclaimed.	_____ (Legal Instruments Examiner) (Date)		ISSUE BATCH NUMBER	

WARNING:
The information disclosed herein may be restricted. Unauthorized disclosure may be prohibited by the United States Code of Federal Regulations, Title 35, Part 201, Subpart 201.10, which prohibits the disclosure of information contained in a patent application to the public before the patent is granted. Possession outside the U.S. Patent & Trademark Office is restricted to authorized employees and contractors only.